



# 30V, N-Channel NexFET™ Power MOSFETs

Check for Samples: CSD17307Q5A

## **FEATURES**

- · Optimized for 5V Gate Drive
- Ultralow Q<sub>g</sub> and Q<sub>gd</sub>
- Low Thermal Resistance
- Avalanche Rated
- Pb Free Terminal Plating
- RoHS Compliant
- Halogen Free
- SON 5-mm × 6-mm Plastic Package

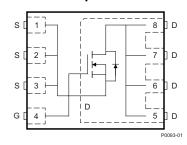
# **APPLICATIONS**

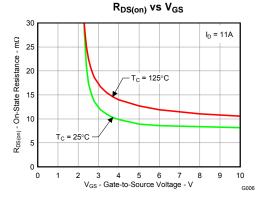
- · Notebook Point of Load
- Point-of-Load Synchronous Buck in Networking, Telecom and Computing Systems

## **DESCRIPTION**

The NexFET™ power MOSFET has been designed to minimize losses in power conversion applications, and optimized for 5V gate drive applications.

## **Top View**





### **PRODUCT SUMMARY**

V <sub>DS</sub>	Drain to Source Voltage 30					
$Q_g$	Gate Charge Total (4.5V) 4					
$Q_{gd}$	Gate Charge Gate to Drain 1					
		$V_{GS} = 3V$	12.8	mΩ		
R <sub>DS(on)</sub>	Drain to Source On Resistance	$V_{GS} = 4.5V$	9.7	mΩ		
		V <sub>GS</sub> = 8V 8.4		mΩ		
$V_{GS(th)}$	Threshold Voltage	1.3	V			

### **ORDERING INFORMATION**

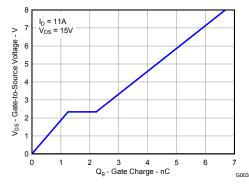
Device	Package	Media	Qty	Ship
CSD17307Q5A	SON 5-mm × 6-mm Plastic Package	13-Inch Reel	2500	Tape and Reel

### **ABSOLUTE MAXIMUM RATINGS**

T <sub>A</sub> = 2	5°C unless otherwise stated	VALUE	UNIT
$V_{DS}$	Drain to Source Voltage	30	٧
$V_{GS}$	Gate to Source Voltage	+10 / -8	٧
	Continuous Drain Current, T <sub>C</sub> = 25°C	73	Α
I <sub>D</sub>	Continuous Drain Current <sup>(1)</sup>	14	Α
I <sub>DM</sub>	Pulsed Drain Current, T <sub>A</sub> = 25°C <sup>(2)</sup>	92	Α
$P_D$	Power Dissipation <sup>(1)</sup>	3	W
T <sub>J</sub> , T <sub>STG</sub>	Operating Junction and Storage Temperature Range	-55 to 150	°C
E <sub>AS</sub>	Avalanche Energy, Single Pulse $I_D=33A,L=0.1mH,R_G=25\Omega$	54	mJ

- (1) Typical  $R_{\theta JA}=41^{\circ} C/W$  on a 1-inch² (6.45-cm²), 2-oz. (0.071-mm thick) Cu pad on a 0.06-inch (1.52-mm) thick FR4 PCB.
- (2) Pulse duration ≤300µs, duty cycle ≤2%

## **GATE CHARGE**



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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## **ELECTRICAL CHARACTERISTICS**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Static Cl	naracteristics					
$BV_{DSS}$	Drain to Source Voltage	$V_{GS} = 0V, I_D = 250\mu A$	30			V
I <sub>DSS</sub>	Drain to Source Leakage Current	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 24V			1	μΑ
I <sub>GSS</sub>	Gate to Source Leakage Current	$V_{DS} = 0V, V_{GS} = +10 / -8V$			100	nA
V <sub>GS(th)</sub>	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	0.9	1.3	1.8	V
		V <sub>GS</sub> = 3V, I <sub>D</sub> = 11A		12.8	17.3	mΩ
R <sub>DS(on)</sub>	Drain to Source On Resistance	$V_{GS} = 4.5V, I_D = 11A$		9.7	12.1	mΩ
		$V_{GS} = 8V$ , $I_D = 11A$		8.4		mΩ
9 <sub>fs</sub>	Transconductance	V <sub>DS</sub> = 15V, I <sub>D</sub> = 11A		66		S
Dynamic	: Characteristics	•			•	
C <sub>iss</sub>	Input Capacitance			535	700	pF
C <sub>oss</sub>	Output Capacitance	V <sub>GS</sub> = 0V, V <sub>DS</sub> = 15V, f = 1MHz		290	375	pF
C <sub>rss</sub>	Reverse Transfer Capacitance			28	36	pF
$R_G$	Series Gate Resistance			0.9	1.8	Ω
Qg	Gate Charge Total (4.5V)			4	5.2	nC
$Q_{gd}$	Gate Charge Gate to Drain	V <sub>DS</sub> = 15V, I <sub>D</sub> = 11A		1		nC
Q <sub>gs</sub>	Gate Charge Gate to Source			1.3		nC
Q <sub>g(th)</sub>	Gate Charge at Vth			0.65		nC
Q <sub>oss</sub>	Output Charge	V <sub>DS</sub> = 13V, V <sub>GS</sub> = 0V		7.3		nC
t <sub>d(on)</sub>	Turn On Delay Time			4.6		ns
t <sub>r</sub>	Rise Time	V 45V V 45V L 44A D 20		6.7		ns
t <sub>d(off)</sub>	Turn Off Delay Time	$V_{DS} = 15V, V_{GS} = 4.5V, I_{DS} = 11A, R_G = 2\Omega$		9.3		ns
t <sub>f</sub>	Fall Time			2.6		ns
Diode Cl	haracteristics				,	
V <sub>SD</sub>	Diode Forward Voltage	I <sub>SD</sub> = 11A, V <sub>GS</sub> = 0V		0.85	1	V
$Q_{rr}$	Reverse Recovery Charge	\/ - 12\/   - 11\ di/dt - 200\/		13		nC
t <sub>rr</sub>	Reverse Recovery Time	$V_{DD}$ = 13V, $I_F$ = 11A, di/dt = 300A/ $\mu$ s		16		ns

## THERMAL CHARACTERISTICS

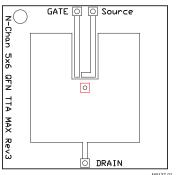
 $(T_{\Delta} = 25^{\circ}C \text{ unless otherwise stated})$ 

(. A _					
	PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Thermal Resistance Junction to Case <sup>(1)</sup>			1.9	°C/W
$R_{\theta,JA}$	Thermal Resistance Junction to Ambient <sup>(1)(2)</sup>			52	°C/W

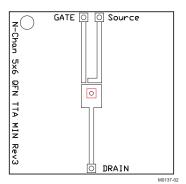
 $R_{\theta JC}$  is determined with the device mounted on a 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu pad on a 1.5-inch × 1.5-inch (3.81-cm × 3.81-cm), 0.06-inch (1.52-mm) thick FR4 PCB.  $R_{\theta JC}$  is specified by design, whereas  $R_{\theta JA}$  is determined by the user's board design. Device mounted on FR4 material with 1-inch<sup>2</sup> (6.45-cm<sup>2</sup>), 2-oz. (0.071-mm thick) Cu.

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Max  $R_{\theta JA} = 52^{\circ} C/W$  when mounted on 1 inch² (6.45 cm²) of 2-oz. (0.071-mm thick) Cu.



Max  $R_{\theta JA} = 121^{\circ} C/W$  when mounted on a minimum pad area of 2-oz. (0.071-mm thick) Cu.

# TYPICAL MOSFET CHARACTERISTICS

(T<sub>A</sub> = 25°C unless otherwise stated)

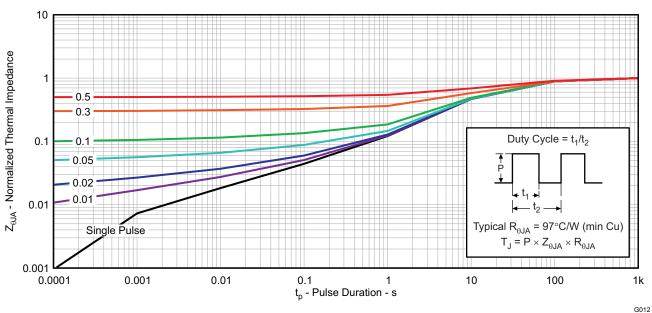


Figure 1. Transient Thermal Impedance



# **TYPICAL MOSFET CHARACTERISTICS (continued)**

 $(T_A = 25^{\circ}C \text{ unless otherwise stated})$ 

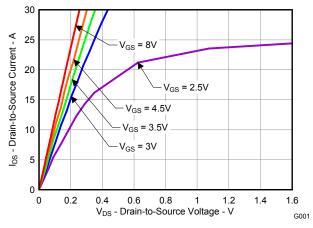


Figure 2. Saturation Characteristics

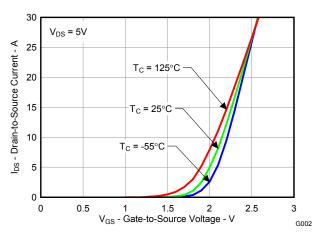


Figure 3. Transfer Characteristics

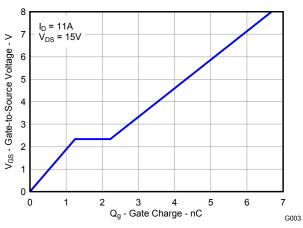


Figure 4. Gate Charge

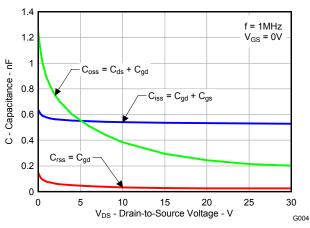


Figure 5. Capacitance

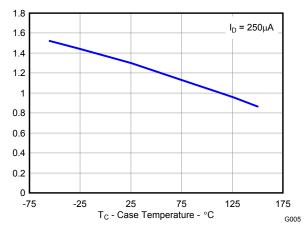


Figure 6. Threshold Voltage vs. Temperature

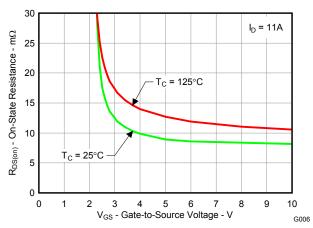


Figure 7. On-State Resistance vs. Gate-to-Source Voltage



# **TYPICAL MOSFET CHARACTERISTICS (continued)**

(T<sub>A</sub> = 25°C unless otherwise stated)

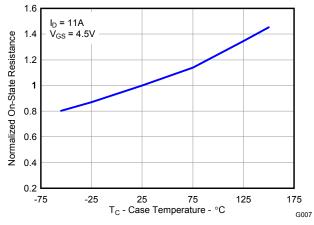


Figure 8. Normalized On-State Resistance vs. Temperature

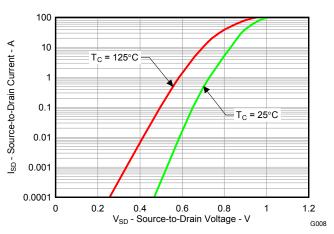


Figure 9. Typical Diode Forward Voltage

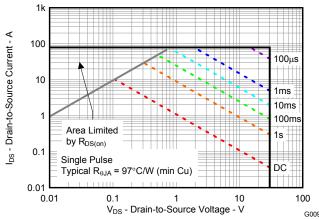


Figure 10. Maximum Safe Operating Area

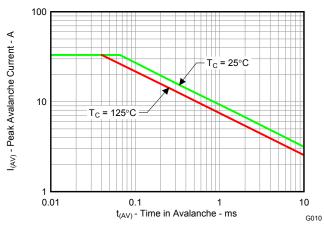


Figure 11. Single Pulse Unclamped Inductive Switching

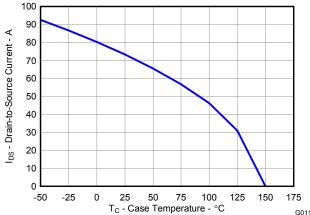
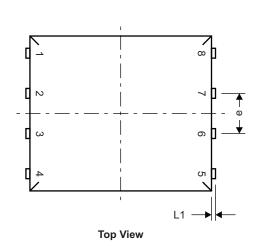


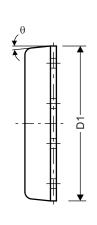
Figure 12. Maximum Drain Current vs. Temperature



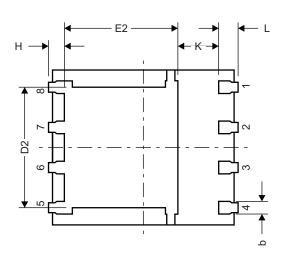
# **MECHANICAL DATA**

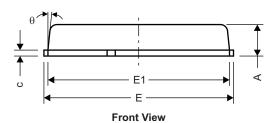
# **Q5A Package Dimensions**





Side View





**Bottom View** 

M0135-01

DIM		MILLIMETERS	
DIM	MIN	NOM	MAX
Α	0.90	1.00	1.10
b	0.33	0.41	0.51
С	0.20	0.25	0.34
D1	4.80	4.90	5.00
D2	3.61	3.81	4.02
E	5.90	6.00	6.10
E1	5.70	5.75	5.80
E2	3.38	3.58	3.78
е	1.17	1.27	1.37
Н	0.41	0.56	0.71
K	1.10		
L	0.51	0.61	0.71
L1	0.06	0.13	0.20
θ	0°		12°

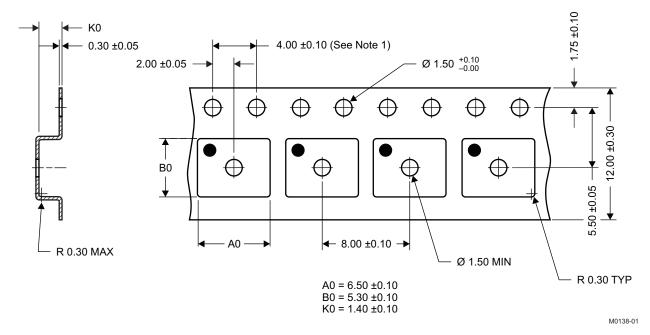


Recommended PCB	Pattern
F6 - F1	F7
F10 F10	M0139-01  4  7  4  7  7  7  7  7  7  7  7  7  7

DIM	MILLIN	METERS	INC	HES
DIN	MIN	MAX	MIN	MAX
F1	6.205	6.305	0.244	0.248
F2	4.46	4.56	0.176	0.18
F3	4.46	4.56	0.176	0.18
F4	0.65	0.7	0.026	0.028
F5	0.62	0.67	0.024	0.026
F6	0.63	0.68	0.025	0.027
F7	0.7	0.8	0.028	0.031
F8	0.65	0.7	0.026	0.028
F9	0.62	0.67	0.024	0.026
F10	4.9	5	0.193	0.197
F11	4.46	4.56	0.176	0.18

For recommended circuit layout for PCB designs, see application note SLPA005 – Reducing Ringing Through PCB Layout Techniques.

# **Q5A Tape and Reel Information**



#### Notes:

- 1. 10-sprocket hole-pitch cumulative tolerance ±0.2
- 2. Camber not to exceed 1mm in 100mm, noncumulative over 250mm
- 3. Material: black static-dissipative polystyrene
- 4. All dimensions are in mm (unless otherwise specified)
- 5. A0 and B0 measured on a plane 0.3mm above the bottom of the pocket



# **REVISION HISTORY**

C	hanges from Original (February 2010) to Revision A	Page
•	Updated the Q5A Package Dimensions table. DIM c MAX was 0.30, DIM D2 MAX was 3.96, DIM e MIN was blank MAX was blank, DIM H NOM was 0.51 MAX was 0.61	6
•	Deleted Note 6 from the Q5A Tape and Reel Information - "MSL1 260°C (IR and convection) PbF reflow compatible"	7
•	Deleted the Package Marking Information section	7



# PACKAGE OPTION ADDENDUM

7-Jan-2016

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CSD17307Q5A	ACTIVE	VSONP	DQJ	8	2500	Pb-Free (RoHS Exempt)	CU SN	Level-1-260C-UNLIM	-55 to 150	CSD17307	Samples

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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7-Jan-2016

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